

What is claimed is:

1. A transmitter chip comprising:  
a first series of phase shifters to control the scan angle and linear polarization of  
an RF signal;
- 5 a 90° phase shifter to control the circular polarization of an RF signal; and  
a means for controlling the first series of phase shifters and the 90° phase shifter.
2. The transmitter chip of claim 1, wherein the means comprises a serial-to-parallel  
converter.
3. The transmitter chip of claim 1, wherein the first series of phase shifters  
10 comprises a 5.625° phase shifter, an 11.25° phase shifter, a 22.5° phase shifter, a 45°  
phase shifter, and a 90 ° phase shifter.
4. The transmitter chip of claim 1, wherein the first series of phase shifters further  
comprises a 3-bit attenuator and three single stage amplifiers.
5. The transmitter chip of claim 1, wherein transistor-transistor logic (TTL) is used  
15 to control the polarization and scan angle of an RF signal.
6. The transmitter chip of claim 1, wherein the transmitter chip is capable of  
generating a signal with a polarization angle in the range of about 0° to 90°.
7. The transmitter chip of claim 1, wherein the transmitter chip is capable of  
generating a left-hand and right-hand circularly-polarized RF signal.
- 20 8. The transmitter chip of claim 1, wherein the transmitter chip is capable of  
generating a left-hand and right-hand circularly-polarized RF signal with very low axial  
ratios.

9. The transmitter chip of claim 1, wherein the transmitter chip is capable of generating scan angle in the range of about  $-45^{\circ}$  to  $45^{\circ}$ .

10. The transmitter chip of claim 1, wherein the transmitter chip is using multifunctional self-aligned gate process (MSAG).

5 11. The transmitter chip of claim 1, wherein the transmitter chip is capable of providing higher RF yields.

12. An antenna comprising:

a first substrate containing a plurality of transmitter chips, wherein each

transmitter chip is comprised of a first series of phase shifters to control the scan angle  
10 and linear polarization of an RF signal, a first  $90^{\circ}$  phase shifter to control the circular polarization of an RF signal, and a first means for controlling the first series of phase shifters and the first  $90^{\circ}$  phase shifter;

a second substrate containing a plurality of transmitter chips, connected at the  
output of the first substrate, wherein each transmitter chip is comprised of a second series  
15 of phase shifters to control the scan angle and linear polarization of an RF signal, a second  $90^{\circ}$  phase shifter to control the circular polarization of an RF signal, and a second means for controlling the second series of phase shifters and the second  $90^{\circ}$  phase shifter;  
and

a balun substrate connected at the output of the second substrate containing a

20 number of baluns that divides an RF signal into two equal signals that are  $180^{\circ}$  out of phase with each other.

13. The antenna of claim 12 wherein the first substrate receives the first RF signal and the second substrate receives the second RF signal from an interconnect substrate.

14. The antenna of claim 12 wherein the antenna is capable of transmitting with a single operating signal.

5 15. The antenna of claim 12, wherein the balun substrate further comprises a number of radiator elements connected at the output of the baluns.

16. The antenna of claim 15, wherein each of the radiator elements are planar square patch radiator.

17. The antenna of claim 12, wherein each of the substrate is designed using MMIC  
10 technology.

18. The antenna of claim 12, wherein each of the substrate is built using LTCC technology.

19. The antenna of claim 12, wherein the various substrates are interconnected using a Fuzz-bottom interconnect.

15 20. The antenna of claim 12, wherein each of the substrate is connected to a aluminum-graphite frame that provides support and heat sinking mechanism for the substrates.

21. The antenna of claim 19, wherein various substrates are connected to the Fuzz-bottom interconnect using a film epoxy.

20 22. A transmitter chip comprising:  
means for controlling the scan angle and the linear polarization of an RF signal;  
and

means for controlling the circular polarization of an RF signal.

23. The transmitter chip of claim 22, wherein the means for controlling the circular polarization of an RF signal can generate left-hand circularly polarized signal and right-hand circularly polarized signal.

5 24. The transmitter chip of claim 23, wherein the means for controlling the circular polarization of an RF signal can generate left-hand circularly polarized signal and right-hand circularly polarized signal with a very low axial ratio.

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